

SOT-143 ESD 静电保护二极管

■ Features 特点

Un-directional ESD Protection 单向静电保护

Low capacitance 低电容

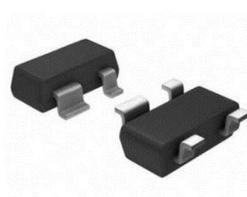
■ Applications 应用

Mobile and cordless phones 移动和子母电话

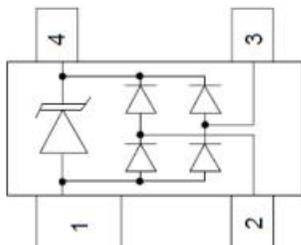
DVI and HDMI interfaces 数字视频和高清多媒体接口

Personal Digital Assistants 个人数码助手

Notebooks, Printers and PCs 笔记本、打印机和电脑



■ Internal Schematic Diagram 内部结构



■ Absolute Maximum Ratings 最大额定值

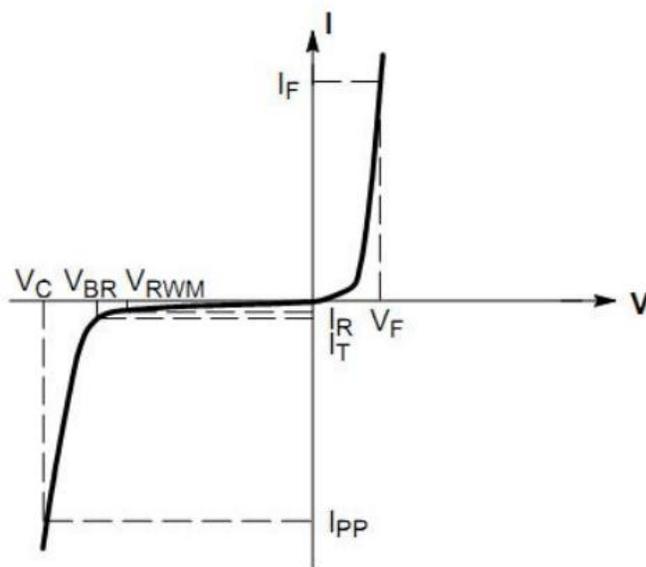
Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位
ESD (IEC61000-4-2 contact discharge) @25°C接触放电	V_{ESD}	± 13	KV
ESD (IEC61000-4-2 air discharge) @25°C空气放电	V_{ESD}	± 18	KV
Peak Pulse Power @25°C峰值脉冲功率	P_{PK}	150	W
Peak Pulse Current @25°C峰值脉冲电流	I_{PP}	5	A
Lead Temperature 管脚温度	T_L	260	°C
Lead Solder Time 管脚焊接时间	T_L	10	S
Operating Temperature 工作温度	T_{op}	-40~85	°C
Junction Temperature 结温	T_J	-55~125	°C
Storage Temperature 储存温度	T_{stg}	-55~150	°C

■ **Electrical Characteristics 电特性**

($T_A=25^\circ\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic Parameters 特性参数	Symbol 符号	Min 最小值	Typ 典型值	Max 最大值	Unit 单位	Condition 条件
Reverse Stand-off Voltage 反向工作电压	V_{RWM}			5	V	
Reverse Breakdown Voltage 反向击穿电压	V_{BR}	6			V	$I_T=1\text{mA}$
Reverse Leakage Current 反向漏电流	I_R			1	μA	$V_{RWM}=5\text{V}$
Clamping Voltage 钳位电压	V_C			15	V	$I_{PP}=1\text{A}$, $t_p=8/20\mu\text{s}$
Clamping Voltage 钳位电压	V_C			30	V	$I_{PP}=5\text{A}$, $t_p=8/20\mu\text{s}$
Diode Capacitance 二极管电容	C_D	I/O to GND Between I/O	1.0 0.5		pF	$V_R=0\text{V}$, $f=1\text{MHz}$

V_{RWM}	Reverse Working Voltage 反向工作电压
$V_{R(BR)}$	Reverse Breakdown Voltage 反向击穿电压@ $I_T=1\text{mA}$
I_T	Test Current 测试电流
I_R	Reverse Leakage Current 反向漏电流@ V_{RWM}
V_C	Clamping Voltage 钳位电压
I_{PP}	Reverse Peak Pulse Current 浪涌电流
C_D	Diode Capacitance 二极管电容 $V_{I0}=0\text{V}$, $V_{P-P}=30\text{mV}$, $f=1\text{MHz}$



■ Typical Characteristic Curve 典型特性曲线

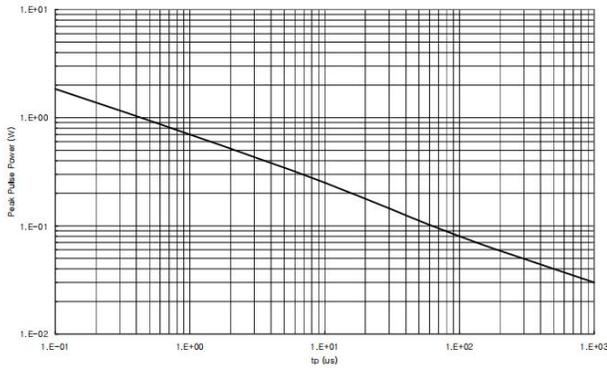


Figure 1. Peak Pulse Power Derating

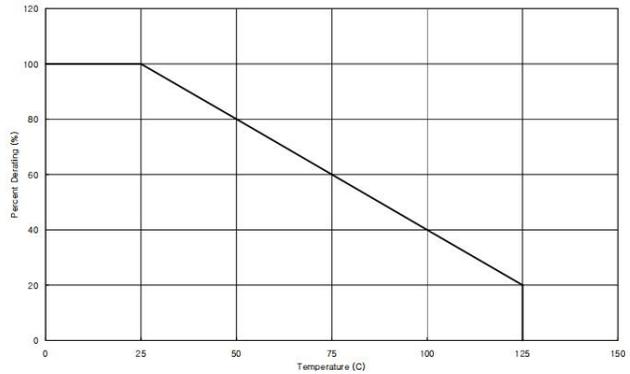


Figure 2. Peak Pulse Power Derating vs Temperature

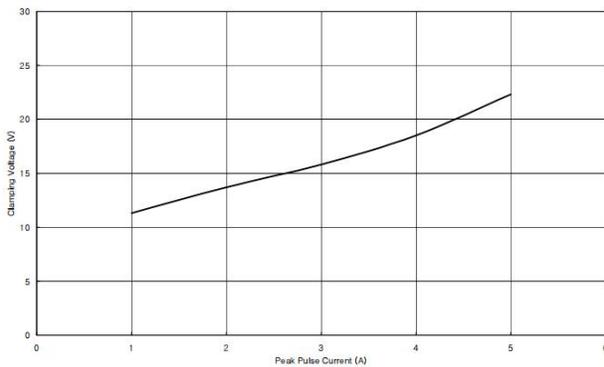


Figure 3. Peak Pulse Current vs Clamping Voltage

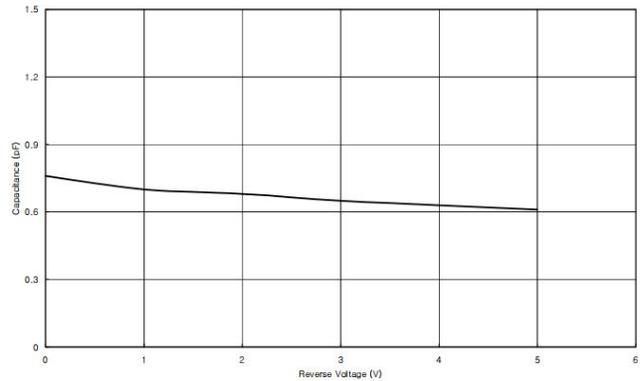
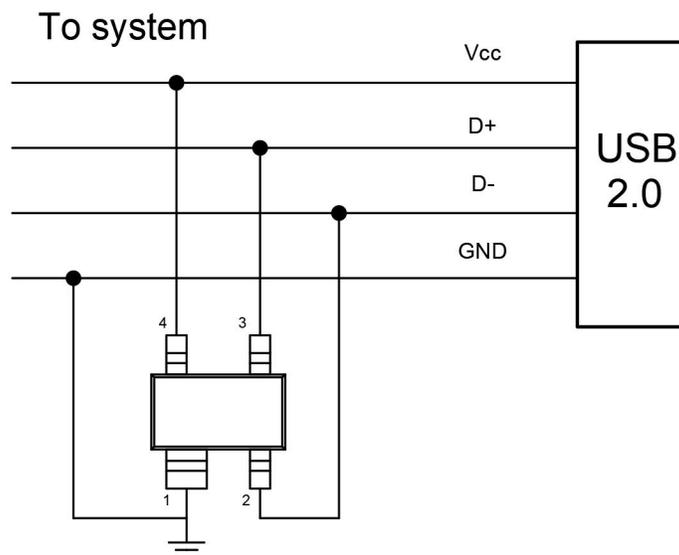
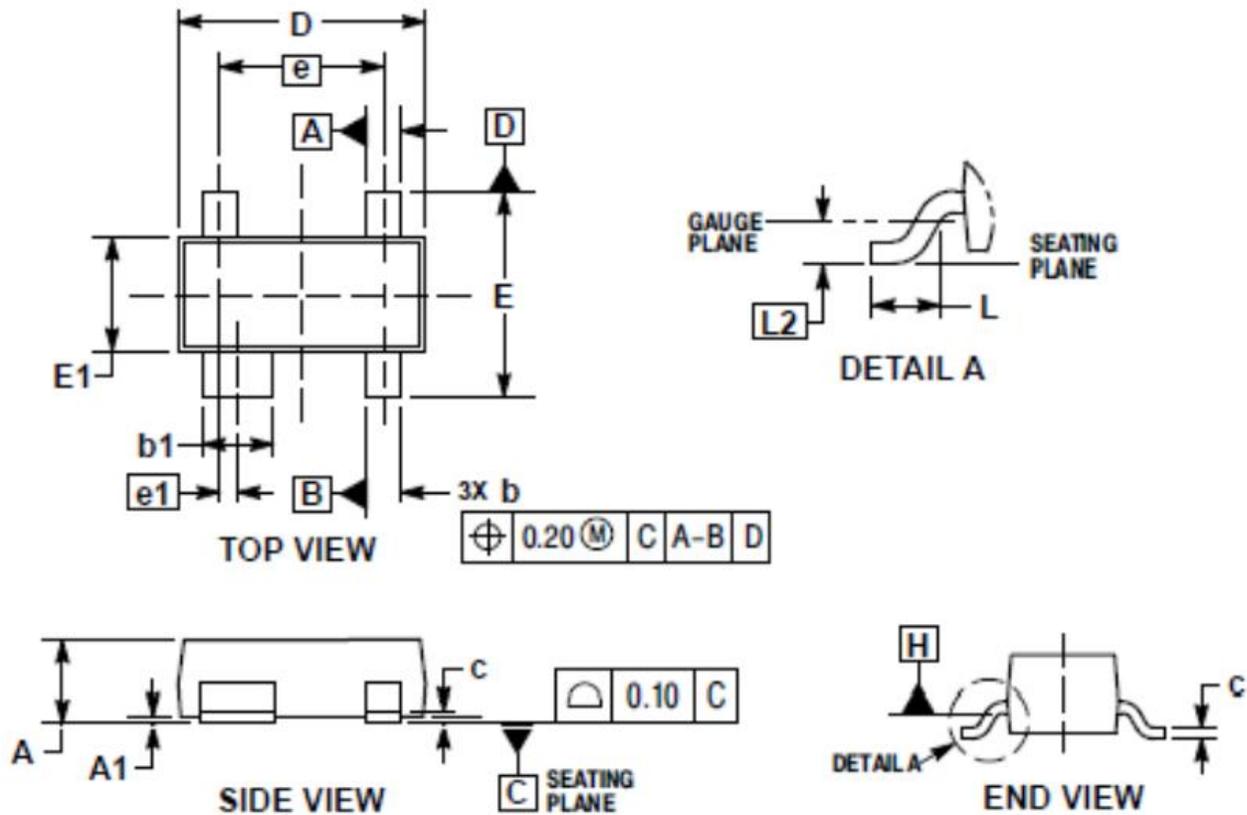


Figure 4. Reverse Voltage vs Capacitance

■ Typical Application 典型应用



■ Dimension 外形封装尺寸



DIM	MILLIMETERS	
	MIN	MAX
A	0.80	1.12
A1	0.01	0.15
b	0.30	0.51
b1	0.76	0.94
c	0.08	0.20
D	2.80	3.05
E	2.10	2.64
E1	1.20	1.40
e	1.92 BSC	
e1	0.20 BSC	
L	0.35	0.70
L2	0.25 BSC	